

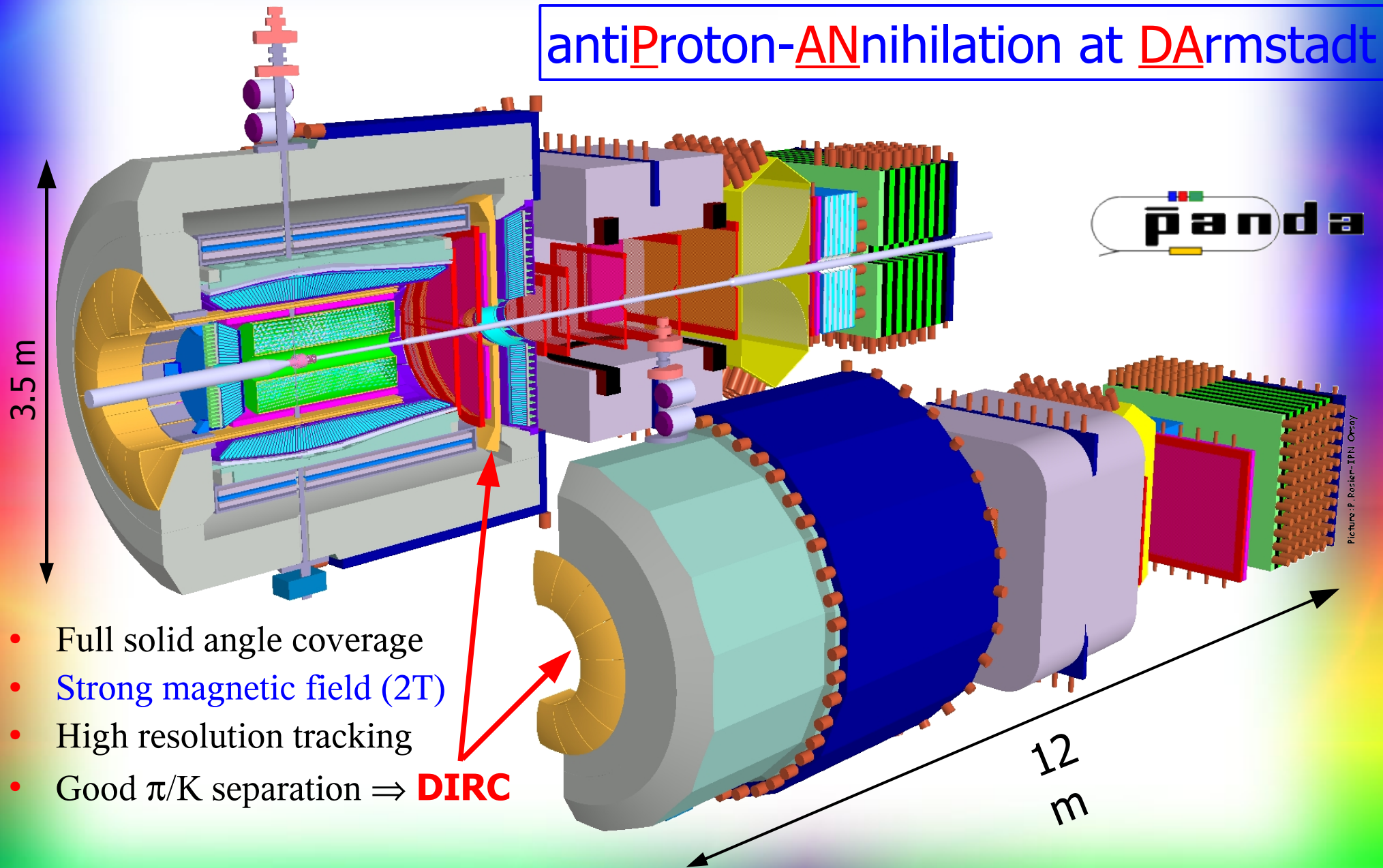
Erlangen Plans with SiPMs

Albert Lehmann, Erlangen University

- particle identification with PANDA
 - experiences with MCP-PMTs
 - first looks at SiPMs
 - plans

PANDA Detector

antiProton-ANnihilation at DArmstadt



Technical Challenges to Photon Sensors

- Single photon detection inside high B-field
 - **high gain** ($> 5 \cdot 10^5$) even in the 2 Tesla magnetic field
- Time resolution to separate π/K with TOP
 - **very good time resolution** of < 50 ps for single photons
- Photon rates in the MHz regime
 - **high rate stability** (rates of several MHz/cm²)
 - short pulses (< 10 ns) to avoid pile-up
 - **long lifetime**
- Few photons per track
 - **high detection efficiency** $\eta = QE * CE * GE$
[QE = quantum efficiency; CE = collection efficiency; GE = geometrical efficiency]
 - **low dark count rate**

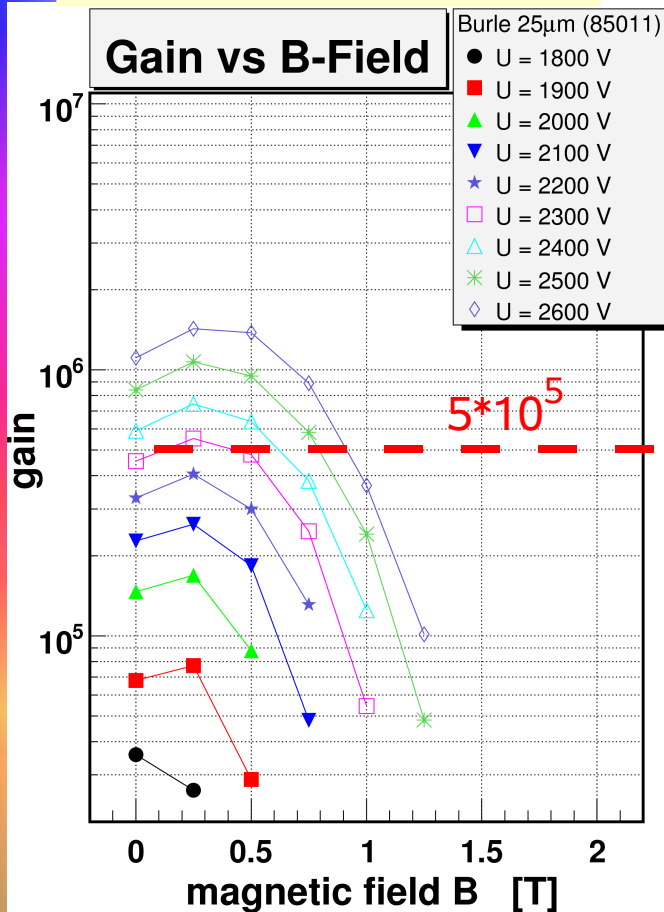
Sensor Candidates

good geometrical resolution over a large surface needed
→ **multi-pixel sensors**

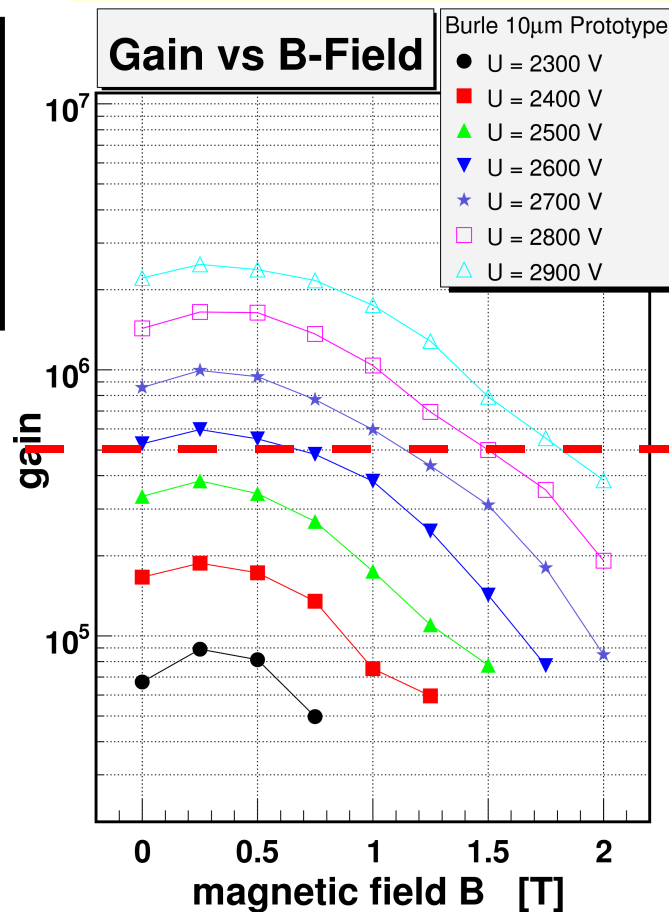
- multi-anode photomultipliers (MaPMTs)
 - (more or less) ruled out by magnetic field
- hybrid photo detectors (HPDs)
 - too bulky
- **micro-channel plate photomultipliers** (MCP-PMTs)
 - problems with lifetime and rate stability
- **Geiger-mode avalanche photo diodes** (SiPMs)
 - noise problematic

MCP-PMT Gain in Magnetic Field

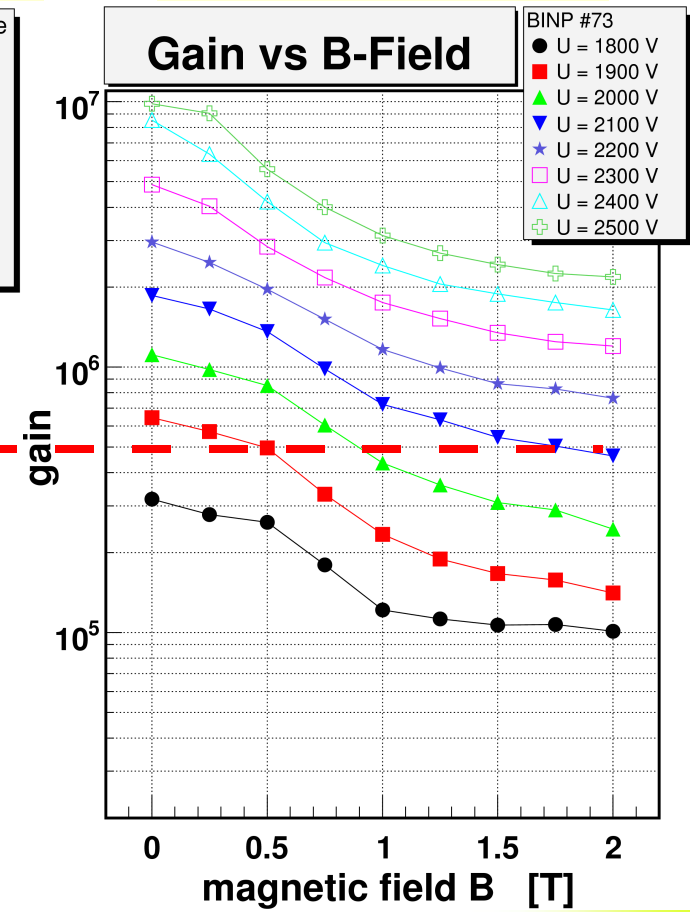
Burle 85011 (25 μm)



Burle Prototype (10 μm)



BINP #73 (6 μm)



pore size $\leq 10 \mu\text{m}$ needed for single photon detection in 2 T field

MCP-PMT Time Resolution

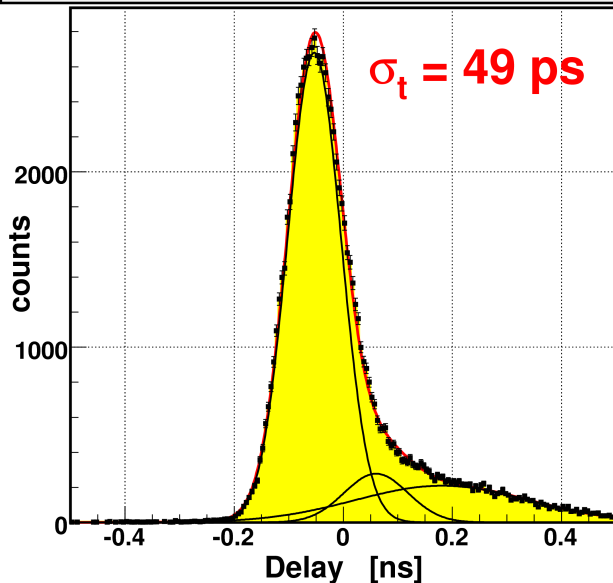
Amplifier Ortec VT120A (x200; 350 Mhz) --- Discriminator LeCroy 821

Burle 85011 (25 μ m)

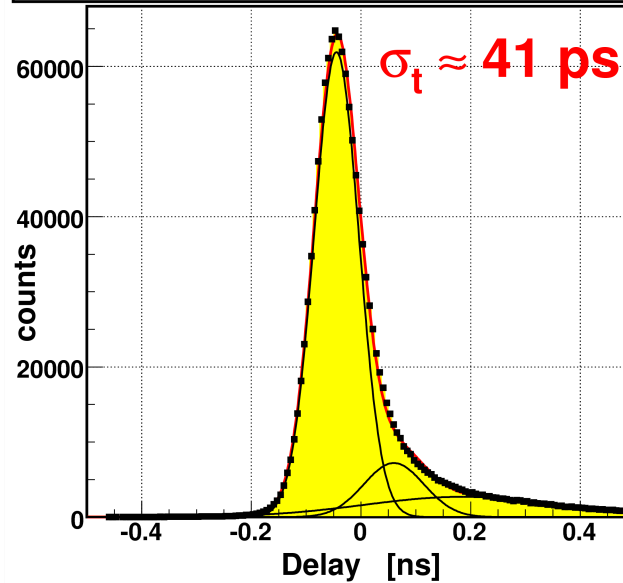
Burle Prototype (10 μ m)

BINP #73 (6 μ m)

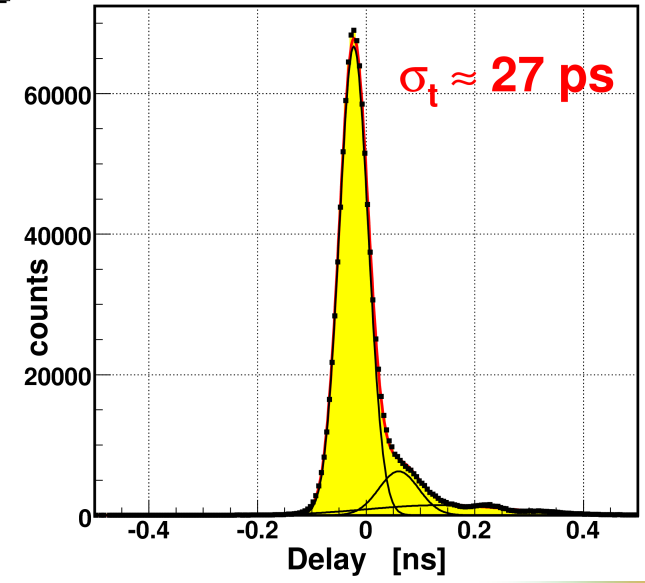
Time Resolution (Q > -0.08 pC && Q < -0.02 pC)



Time Resolution (Q > -0.50 pC && Q < -0.25 pC)

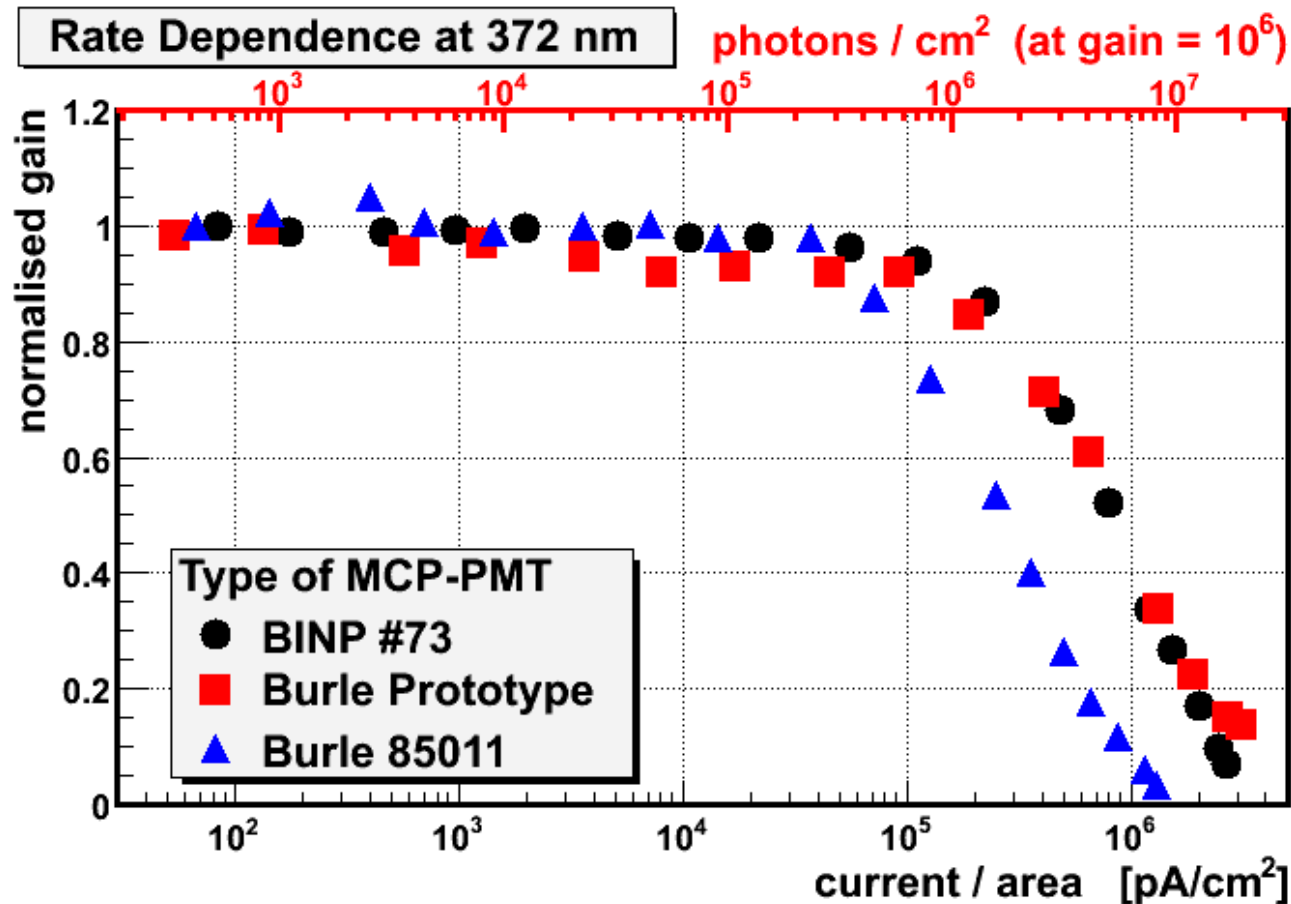


Time Resolution (Q > -0.45 pC && Q < -0.10 pC)



- single photon resolutions corrected for electronics and laser width
 - Burle 85011 (25 μ m) **45 ps**
 - Burle Prototype (10 μ m) **37 ps**
 - BINP #73 (6 μ m) **20 ps**

MCP-PMT Rate Stability



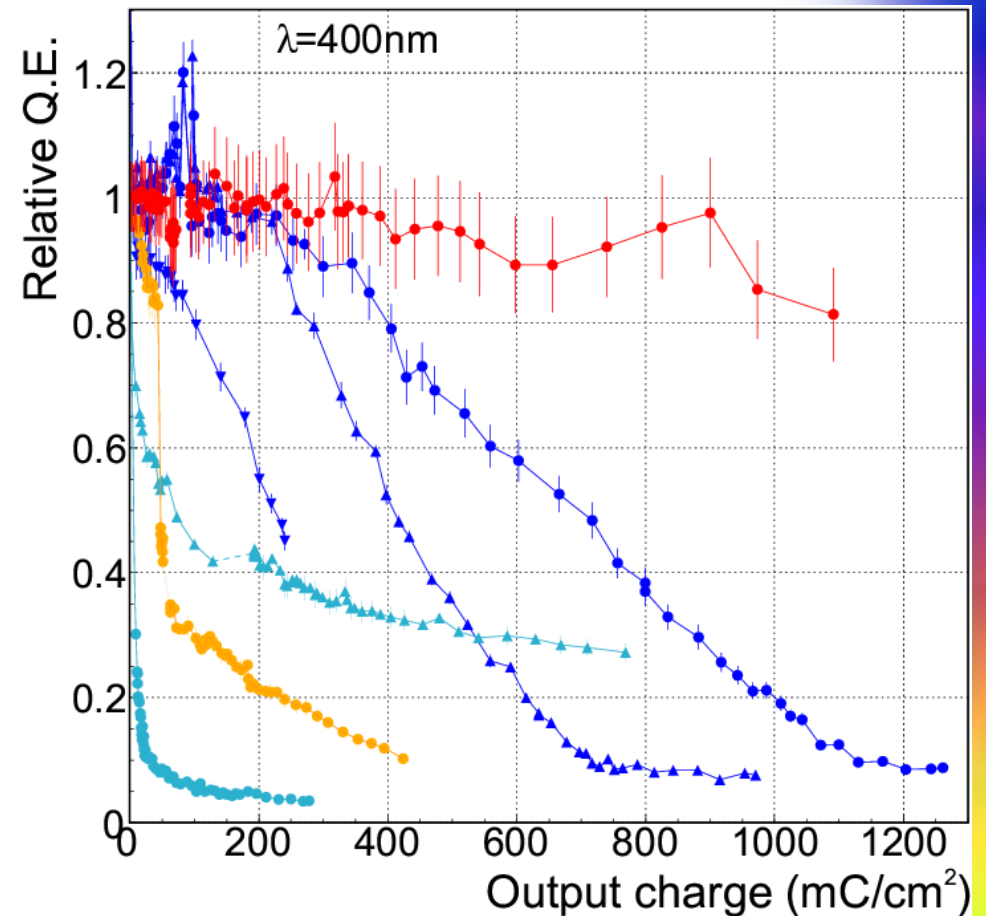
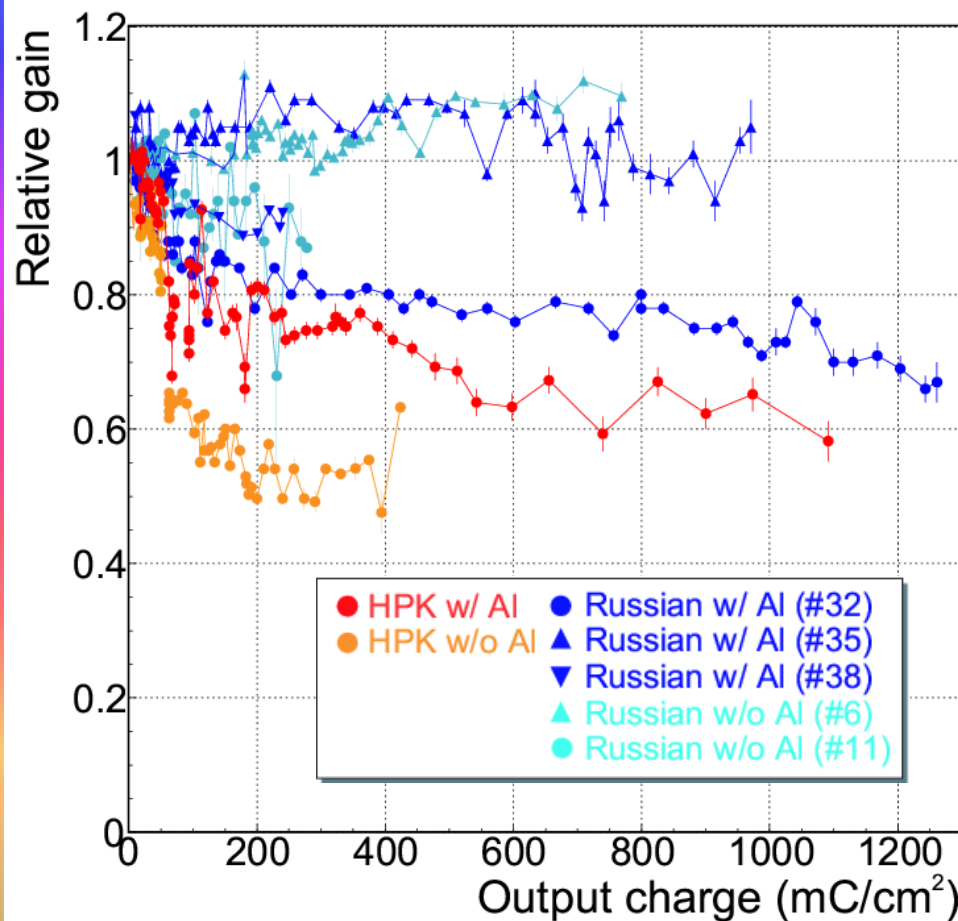
- usually stable operation to about 1 MHz/cm² photons
- dark count rates typically several kHz/cm²

MCP-PMT Lifetime

Gain

T. Ohshima (Nagoya)
Talk at SLAC 2006

Quantum Efficiency



- fast gain drop first and almost constant later
- Q.E. of HPK w Al-protection almost stable up to 3.5 C/cm²

Overview of Sensor Performances

	DIRC required	MaPMT	MCP-PMT	SiPM
Gain at 0 T [$\cdot 10^6$]	--	1 to 10	1 to 10	0.5 to 1
Gain at 2 T [$\cdot 10^6$]	> 0.5	0	> 0.5	
Time resolution [ps]	< 50	150	< 50	100
Rate stability [MHz/cm ²]	~ 10	10	1	
Darkcount rate [kHz/cm ²]	< 10	~ 0.01	2	10000
Crosstalk behaviour		okay	moderate	
Lifetime [C/cm ²]	100		> 3.5	

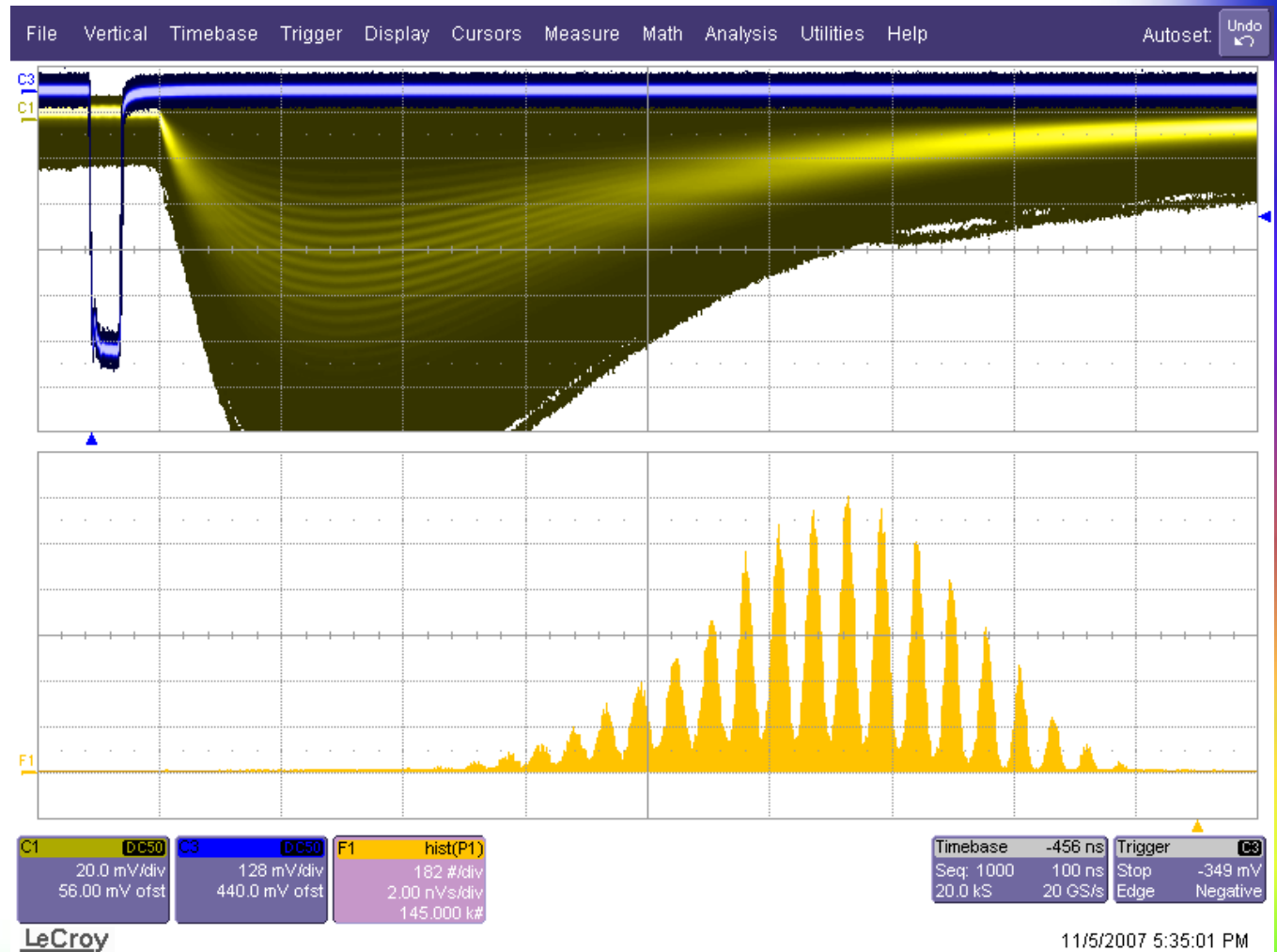
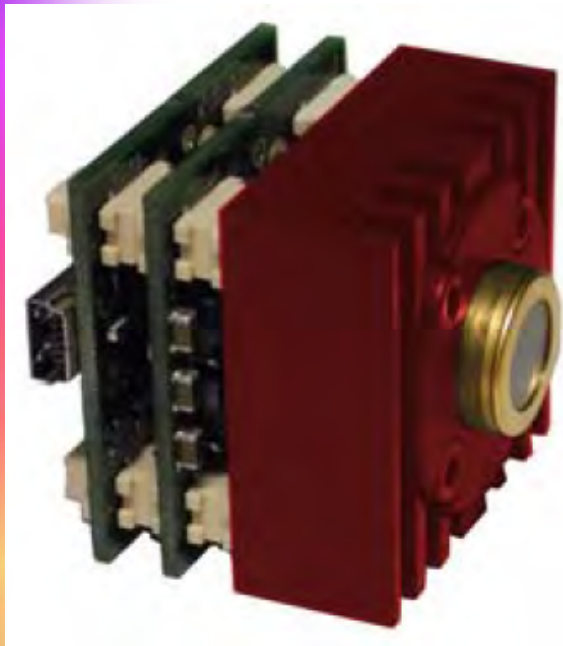
- currently there is no sensor fulfilling all requirements of the PANDA DIRC

SiPMs for PANDA DIRC?

- Advantages compared to MCP-PMTs
 - probably higher rate stability
 - higher quantum efficiency
 - probably longer lifetime
- Disadvantages compared to MCP-PMTs
 - low geometrical efficiency
 - worse time resolution
 - behaviour in radiation environment?
 - **enormous dark count rates at room temperature**
 - very expensive because coverage of large area necessary

SensL SPMMMini (1x1 mm²)

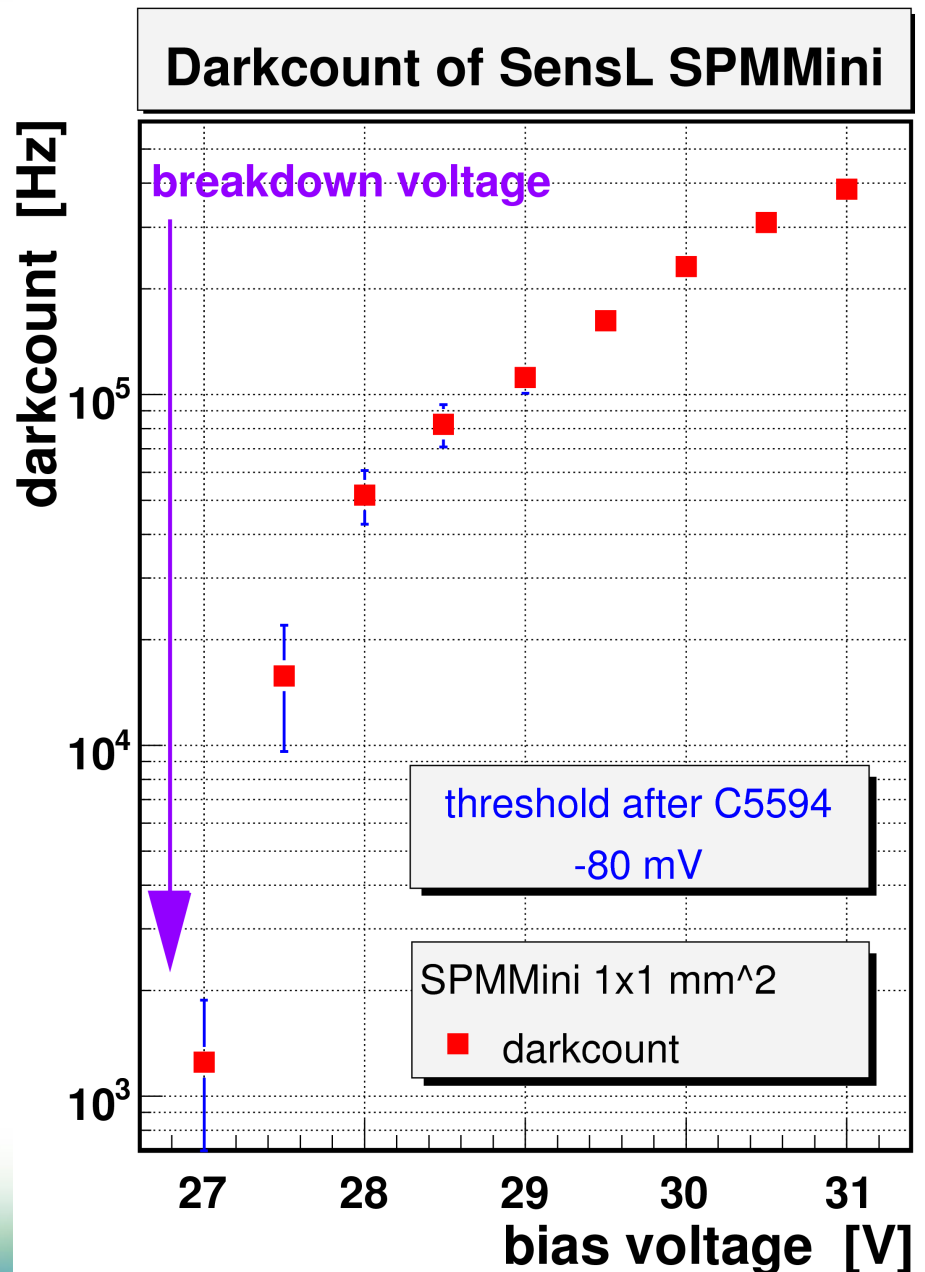
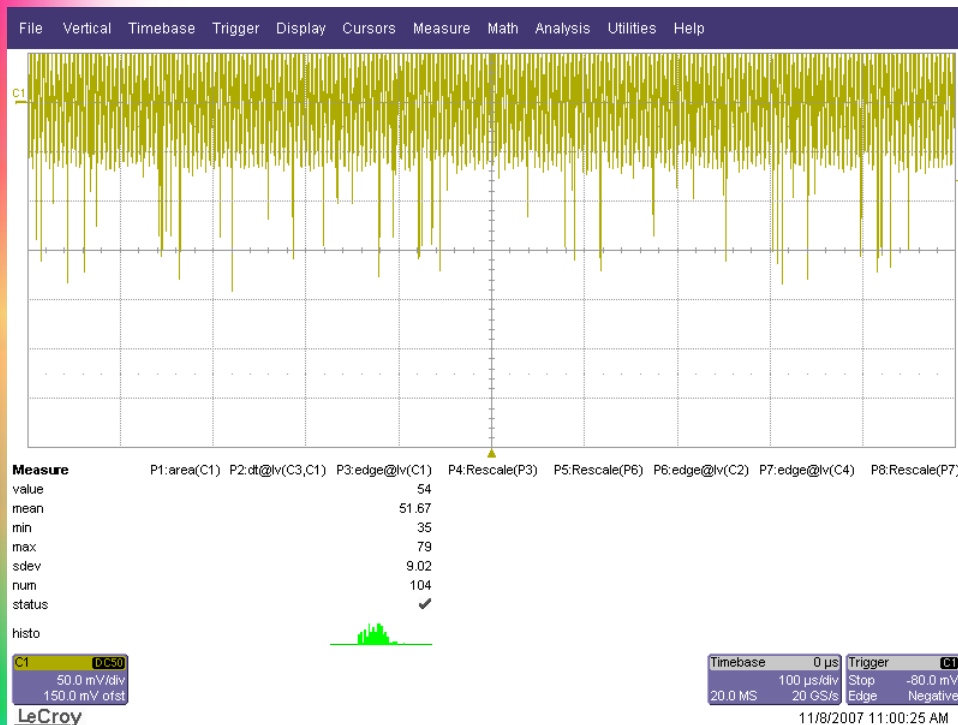
Test module: electronics (“wrong” amplifier + Peltier-Cooling) attached



very long signals (~300 ns width, >1 μs long)

SensL SPMMMini – Dark Count

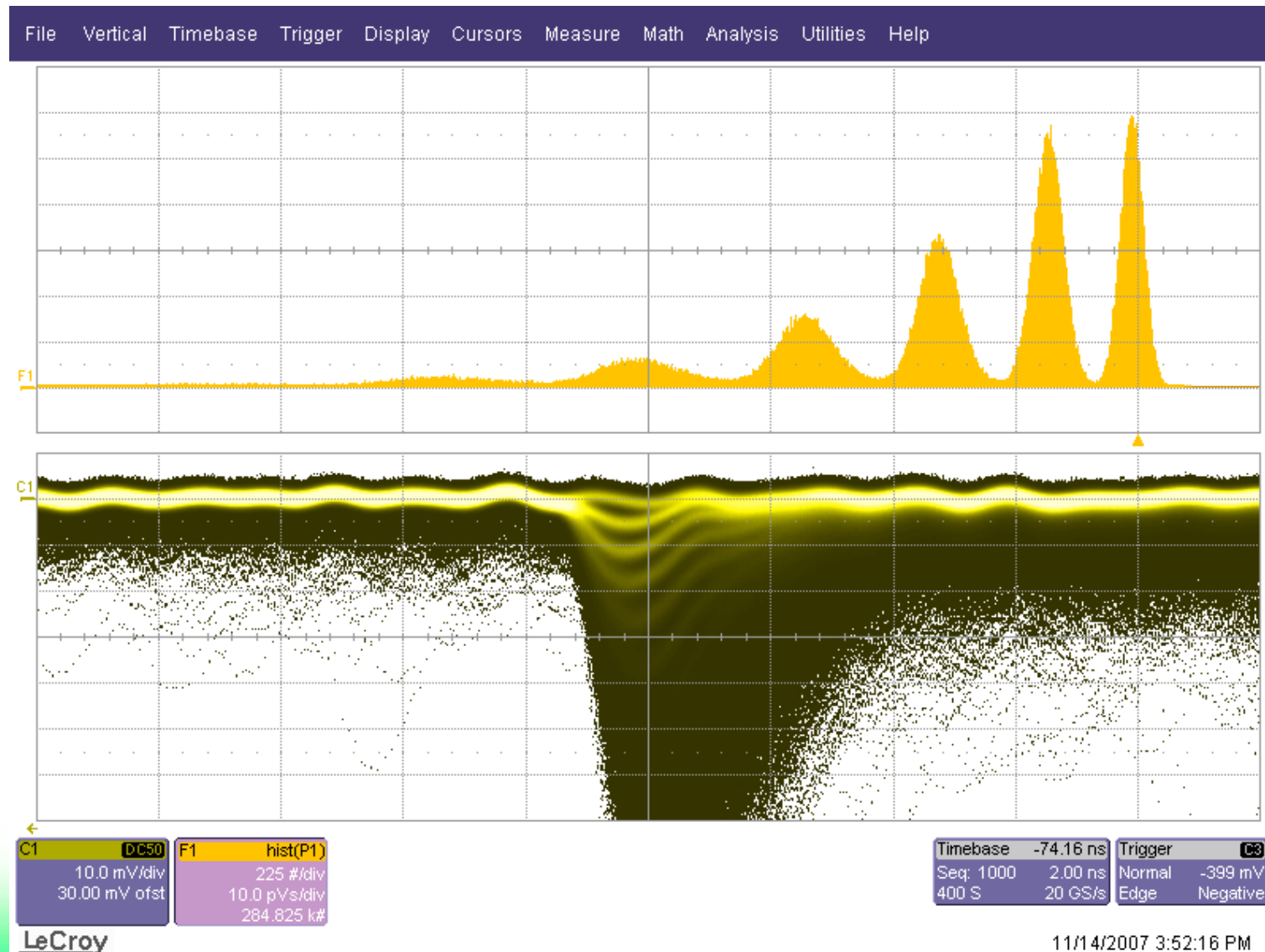
- Size of SPMMMini: $1 \times 1 \text{ mm}^2$
- 920 pixels
- Test module with readout electronics and Peltier cooling
- **Dark count cooled $>100 \text{ kHz}$**



Hamamatsu MPPC (S10362-11-050U)

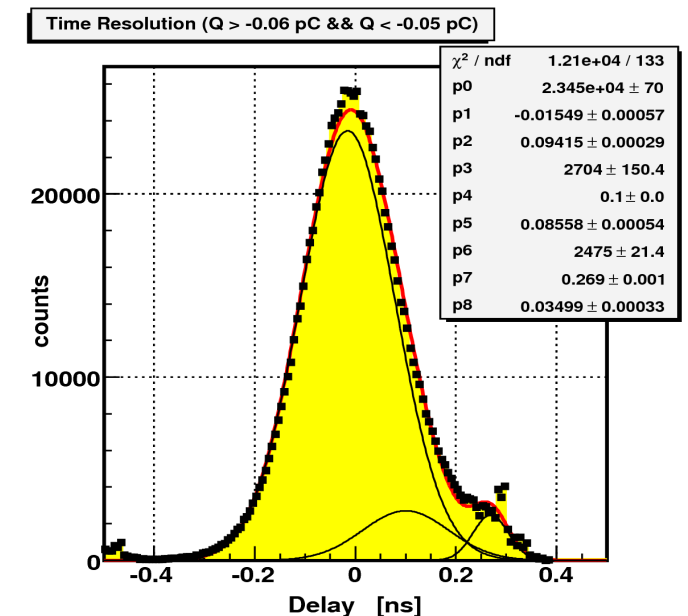
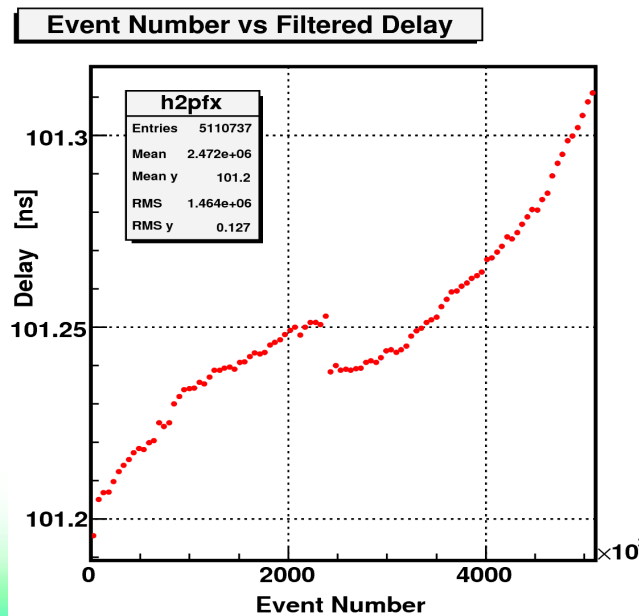
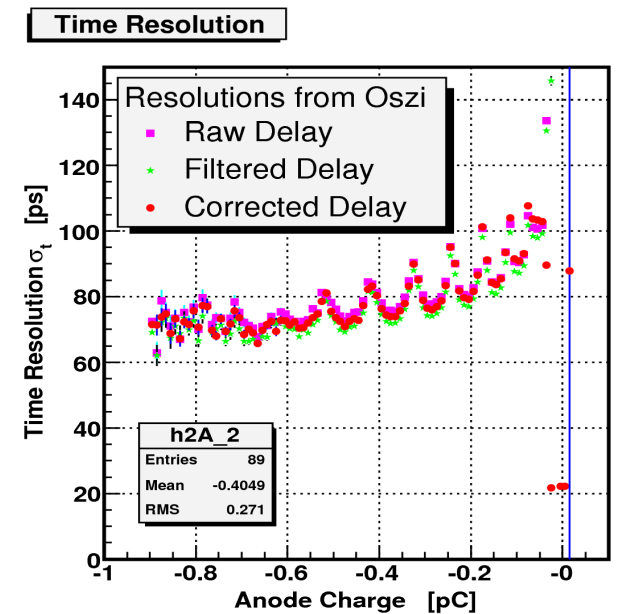
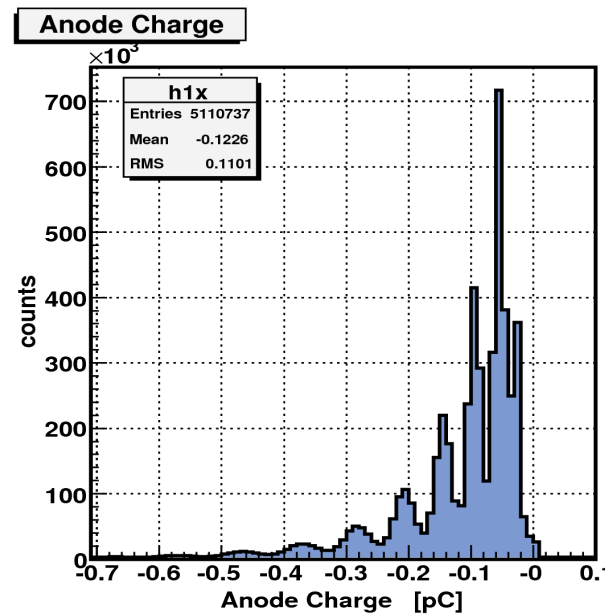
50 μm pixels module: 1x1 mm^2 ; amplification with VT120A (200x)

very short signals (~ 2 ns width)



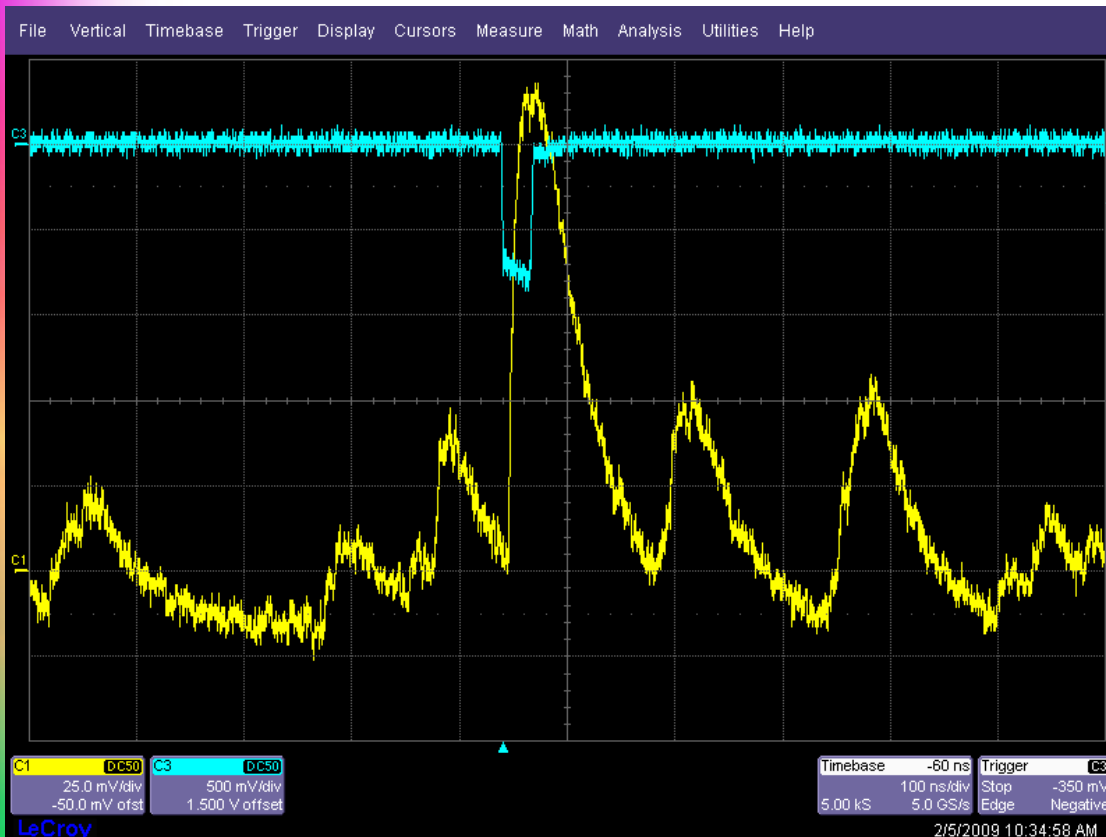
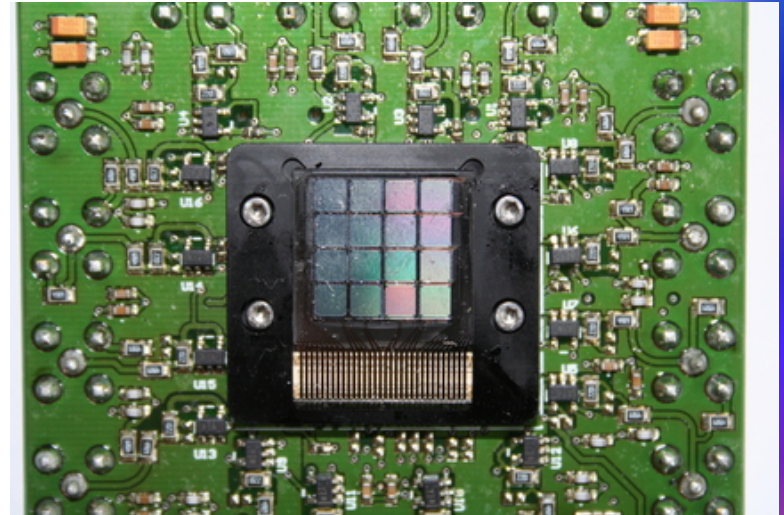
Time Resolution

- Hamamatsu MPPC (S10362-11-050U)
 - 50 μm pixels
 - area: 1x1 mm^2
- self-designed readout circuit
- amplification factor x6300
- measured with oscilloscope
- **single photon time resolution ~ 100 ps**



SensL SPMArray

- active area $12 \times 12 \text{ mm}^2$ with 4×4 channels ($3 \times 3 \text{ mm}^2$ SiPMs with $35 \mu\text{m}$ microcells)
- bias supply and amplification board (x2200 for each channel)



- positive signals
 - fast rise time ($< 10 \text{ ns}$)
 - width $< 100 \text{ ns}$
- enormous dark count rate
 - $\sim 10 \text{ MHz/channel}$ at room temperature
 - a lot of pile-up

Plans with SiPMs

- performance measurements for different SiPM models
 - setup existent
 - single photon time resolution
 - behaviour at high event rates
 - lifetime
- **reduction of dark count rates**
 - sensor cooling
 - setup has to be built
- behaviour in high radiation environments